


**INFORMATION DISCLOSURE
CITATION**

ATTY. DOCKET NO.

SERIAL NO.

4105-73

10/568,770

APPLICANT

CHO ET AL.

(Use several sheets if necessary)

FILING DATE

GROUP

March 21, 2006

1795

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	6,165,622	12/2000	Kijima et al			
	6,197,600 B1	3/2001	Kijima et al			
	5,940,691	8/1999	Manning			
	5,096,550	3/1992	Mayer et al			

FOREIGN PATENT DOCUMENTS

DOCUMENT	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
0 781 736 A	7/1997	EP			
0 878 837 A	11/1998	EP			

OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)

	Cho et al, "Tbit/inch ² ferroelectric data storage ...", Applied Physics Letters, Vol. 81, No. 23, 2 Dec. 2002.
	Hiranaga et al, "Ferroelectric Single Crystal Recording Media ...", Japanese Journal of Applied Physics", Vol. 43, No. 4B, 2004, p. L569-L571. XP-002512248
	Terabe et al, "Microscale to Nanoscale ferroelectric domain and ...", Applied Physics Letters; Vol. 82, No. 3, 20 Jan. 2003.
	Sones et al, "Differential etch rates in z-cut LiNbO ₃ ...", J. Mater. Chem., 2002, 12, 295-298. XP-002511826

*Examiner

Date Considered

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Initial a this form with next communication to applicant.